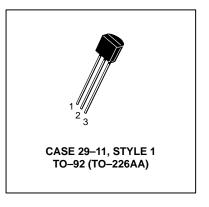


Amplifier Transistor NPN Silicon

MPS4124

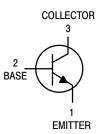
MAXIMUM RATINGS

Rating	Symbol	Value	Unit	
Collector–Emitter Voltage	V _{CE}	25	Vdc	
Collector-Base Voltage	V _{CB}	30	Vdc	
Emitter-Base Voltage	V _{EB}	5.0	Vdc	
Collector Current — Continuous	I _C	200	mAdc	
Total Power Dissipation @ T _A = 25°C Derate above 25°C	P _D	625 5.0	mW mW/°C	
Total Power Dissipation @ T _C = 25°C Derate above 25°C	P _D	1.5 12	W mW/°C	
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to +150	°C	



THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	200	°C/W
Thermal Resistance, Junction to Case	$R_{\theta JC}$	83.3	°C/W



ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector–Emitter Breakdown Voltage (I _C = 1.0 mA, I _B = 0)	V _{(BR)CEO}	25	_	Vdc
Collector–Base Breakdown Voltage ($I_C = 10 \mu A, I_E = 0$)	V _{(BR)CBO}	30	_	Vdc
Emitter–Base Breakdown Voltage ($I_C = 0$, $I_E = 10 \mu A$)	V _{(BR)EBO}	5.0	_	Vdc
Collector Cutoff Current $(V_{CB} = 20 \text{ V}, I_E = 0)$	I _{CBO}	_	50	nAdc
Emitter Cutoff Current $(V_{EB} = 3.0 \text{ V}, I_{C} = 0)$	I _{EBO}	_	50	nAdc

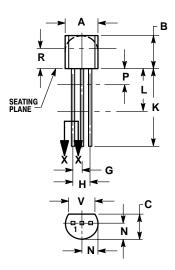
MPS4124

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted) (Continued)

Characteristic	Symbol	Min	Max	Unit
ON CHARACTERISTICS				
DC Current Gain $ (I_C = 2.0 \text{ mA}, V_{CE} = 1.0 \text{ V}) $ $ (I_C = 50 \text{ mA}, V_{CE} = 1.0 \text{ V}) $	h _{FE}	120 60	360 —	_
Collector–Emitter Saturation Voltage ($I_C = 50 \text{ mA}, I_B = 5.0 \text{ mA}$)	V _{CE(sat)}	_	0.3	Vdc
Base–Emitter Saturation Voltage ($I_C = 50 \text{ mA}, I_B = 5.0 \text{ mA}$)	V _{BE(sat)}	_	0.95	Vdc
SMALL-SIGNAL CHARACTERISTICS	-			
Current–Gain — Bandwidth Product ($I_C = 10 \text{ mA}, V_{CE} = 20 \text{ V}, f = 100 \text{ MHz}$)	f _⊤	170	_	MHz
Output Capacitance $(V_{CB} = 5.0 \text{ V}, I_E = 0, f = 1.0 \text{ MHz})$	C _{ob}	_	4.0	pF
Input Capacitance ($V_{EB} = 0.5 \text{ V}, I_{C} = 0, f = 1.0 \text{ MHz}$)	C _{ib}	_	13.5	pF
Small–Signal Current Gain ($I_C = 2.0 \text{ mA}$, $V_{CE} = 1.0 \text{ V}$, $f = 1.0 \text{ kHz}$)	h _{fe}	120	480	_
Noise Figure (I _C = 100 μ A, V _{CE} = 5.0 V, R _S = 1.0 k Ω , f = 1.0 kHz)	NF	_	5.0	dB

PACKAGE DIMENSIONS

TO-92 (TO-226) CASE 29-11 ISSUE AL





- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
 4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
С	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
_	0.015	0.020	0.39	0.50
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
P		0.100		2.54
R	0.115		2.93	
٧	0.135		3.43	

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer.

PUBLICATION ORDERING INFORMATION

NORTH AMERICA Literature Fulfillment:

Literature Distribution Center for ON Semiconductor P.O. Box 5163, Denver, Colorado 80217 USA

Phone: 303–675–2175 or 800–344–3860 Toll Free USA/Canada **Fax**: 303–675–2176 or 800–344–3867 Toll Free USA/Canada

Email: ONlit@hibbertco.com

Fax Response Line: 303-675-2167 or 800-344-3810 Toll Free USA/Canada

N. American Technical Support: 800-282-9855 Toll Free USA/Canada

EUROPE: LDC for ON Semiconductor - European Support

German Phone: (+1) 303–308–7140 (Mon–Fri 2:30pm to 7:00pm CET)

Email: ONlit-german@hibbertco.com

French Phone: (+1) 303–308–7141 (Mon–Fri 2:00pm to 7:00pm CET)

Email: ONlit-french@hibbertco.com

English Phone: (+1) 303–308–7142 (Mon–Fri 12:00pm to 5:00pm GMT)

Email: ONlit@hibbertco.com

EUROPEAN TOLL-FREE ACCESS*: 00-800-4422-3781

*Available from Germany, France, Italy, UK, Ireland

CENTRAL/SOUTH AMERICA:

Spanish Phone: 303-308-7143 (Mon-Fri 8:00am to 5:00pm MST)

Email: ONlit-spanish@hibbertco.com

Toll-Free from Mexico: Dial 01-800-288-2872 for Access -

then Dial 866-297-9322

ASIA/PACIFIC: LDC for ON Semiconductor – Asia Support

Phone: 303-675-2121 (Tue-Fri 9:00am to 1:00pm, Hong Kong Time)

Toll Free from Hong Kong & Singapore:

001-800-4422-3781 Email: ONlit-asia@hibbertco.com

JAPAN: ON Semiconductor, Japan Customer Focus Center 4–32–1 Nishi–Gotanda, Shinagawa–ku, Tokyo, Japan 141–0031

Phone: 81–3–5740–2700 **Email**: r14525@onsemi.com

ON Semiconductor Website: http://onsemi.com

For additional information, please contact your local

Sales Representative.